TJA1463

CAN FD signal improvement transceiver with Sleep mode

Rev. 2 — 15 October 2021

Product data sheet

1 General description

The TJA1463 is a member of the TJA146x family of transceivers that provide an interface between a Controller Area Network (CAN) or CAN FD (Flexible Data rate) protocol controller and the physical two-wire CAN bus. TJA146x transceivers implement the CAN physical layer as defined in ISO 11898-2:2016 and SAE J2284-1 to SAE J2284-5, and are fully interoperable with high-speed Classical CAN and CAN FD transceivers.

The TJA1463 includes CAN Signal Improvement Capability (SIC), as defined in CiA 601-4:2019. CAN signal improvement significantly reduces signal ringing in a network, allowing reliable CAN FD communication to function in larger topologies. In addition, the TJA1463 features a much tighter bit timing symmetry performance to enable CAN FD communication up to 8 Mbit/s.

The TJA1463 is intended as a simple replacement for high-speed Classical CAN and CAN FD transceivers, such as the TJA1043 from NXP. It offers pin compatibility and is designed to avoid changes to hardware and software design, allowing the TJA1463 to be easily retrofitted to existing applications.

An AEC-Q100 Grade 0 variant, the TJR1463, is available for high temperature applications, supporting operation at 150 °C ambient temperature.

2 Features and benefits

2.1 General

- ISO 11898-2:2016, SAE J2284-1 to SAE J2284-5 and SAE J1939-14 compliant
- Implements CAN Signal Improvement Capability as defined in CiA 601-4:2019 to significantly reduce signal ringing effects in a network
- Much tighter bit timing symmetry performance allowing more time to reduce signal ringing
- Low Electromagnetic Emission (EME) and high Electromagnetic Immunity (EMI)
- Qualified according to AEC-Q100 Grade 1
- VIO input for interfacing with 3.3 V to 5 V microcontrollers
- · Listen-only mode for node diagnosis and failure containment
- Available in SO14 and leadless HVSON14 (3.0 mm x 4.5 mm) packages; HVSON14 with improved Automated Optical Inspection (AOI) capability.
- Dark green product (halogen free and Restriction of Hazardous Substances (RoHS) compliant)



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2.2 Predictable and fail-safe behavior

- · Undervoltage detection with defined handling on all supply pins
- Full functionality guaranteed from the undervoltage detection thresholds up to the maximum limiting voltage values
- Defined behavior below the undervoltage detection thresholds
- Transceiver disengages from the bus (high-ohmic) when the battery voltage drops below the Off mode threshold
- Internal biasing of TXD and mode selection input pins, to enable defined fail-safe behavior

2.3 Low-power management

- · Very low-current Standby and Sleep modes, with host, local and bus wake-up capability
- Entire node with TJA1463 can be powered down while still supporting local, bus and host wake-up
- CAN wake-up receiver powered by V_{BAT} allowing V_{IO} and V_{CC} to be shut down
- CAN wake-up pattern filter time of 0.5 μs to 1.8 μs, meeting Classical CAN and CAN FD requirements

2.4 Diagnosis & Protection

- · Overtemperature diagnosis
- Transmit Data (TXD) dominant time-out and TXD-to-RXD short-circuit handler with diagnosis
- Bus dominant failure diagnosis
- Cold start diagnosis (first battery connection)
- High ESD handling capability on the bus pins (6 kV IEC and 8kV HBM)
- Bus pins and VBAT protected against transients in automotive environments
- · Thermally protected

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3 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{BAT}	battery supply voltage		4.5	-	28	V
I _{BAT}	battery supply current	Normal or Listen-only mode	-	80	300	μΑ
		Standby or Sleep mode	-	13	26	μΑ
$V_{uvd(VBAT)}$	undervoltage detection voltage on pin VBAT		4	-	4.5	V
V _{CC}	supply voltage		4.5	-	5.5	V
I _{CC}	supply current	Normal mode, dominant	-	42	70	mA
		Normal mode, recessive	-	7	10	mA
		Listen-only mode	-	5	8	mA
		Standby or Sleep mode	-	-	2	μA
$V_{uvd(VCC)}$	undervoltage detection voltage on pin VCC	V _{BAT} > 4.5 V	4	-	4.5	V
V _{uvhys(VCC)}	undervoltage hysteresis voltage on pin VCC		50	-	-	mV
V _{IO}	supply voltage on pin VIO		2.95	-	5.5	V
I _{IO}	supply current on pin VIO	Normal mode, dominant; V _{TXD} = 0 V	-	90	250	μA
		Normal or Listen-only mode, recessive; $V_{TXD} = V_{IO}$	-	-	3	μΑ
		Standby or Sleep mode	-	-	2	μA
$V_{uvd(VIO)}$	undervoltage detection voltage on pin VIO	V _{BAT} > 4.5 V	2.65	-	2.95	V
V _{uvhys(VIO)}	undervoltage hysteresis voltage on pin VIO		50	-	-	mV
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 on pins CANH and CANL	-6	-	+6	kV
V _{CANH}	voltage on pin CANH	limiting value according to IEC 60134	-36	-	+40	V
V _{CANL}	voltage on pin CANL	limiting value according to IEC 60134	-36	-	+40	V
T_{vj}	virtual junction temperature		-40	-	+150	°C

4 Ordering information

Table 2. Ordering information

Type number	Package	Package							
	Name	Description	Version						
TJA1463AT	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1						
TJA1463ATK	HVSON14	plastic thermal enhanced very thin small outline package; no leads; 14 terminals; body $3\times4.5\times0.85~\text{mm}$	SOT1086-2						

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Table 3. TJA1463 feature overview

See Section 19 for a feature overview of the complete TJx144x/TJx146x/TJF1441 family.

	Modes				Suppl	lies		Data rate Additional features								
Device ^[1]	Normal	Standby	Sleep	Silent/Listen-only	Selectable Off	VCC pin	VIO pin	VBAT pin	Up to 5 Mbit/s CAN FD	Up to 8 Mbit/s CAN FD	Signal improvement ^[2]	Wake-up source recognition ^[3]	Short WUP support [0.5 - 1.8 µs] ^[4]	Single supply pin wake-up ^[5]	TXD dominant timeout	Local diagnostics via ERR_N pin
TJA1463A	•	•	•	•		•	•	•	•	•	•	•	•	•	•	•

TJA1463 is AEC-Q100 Grade 1.

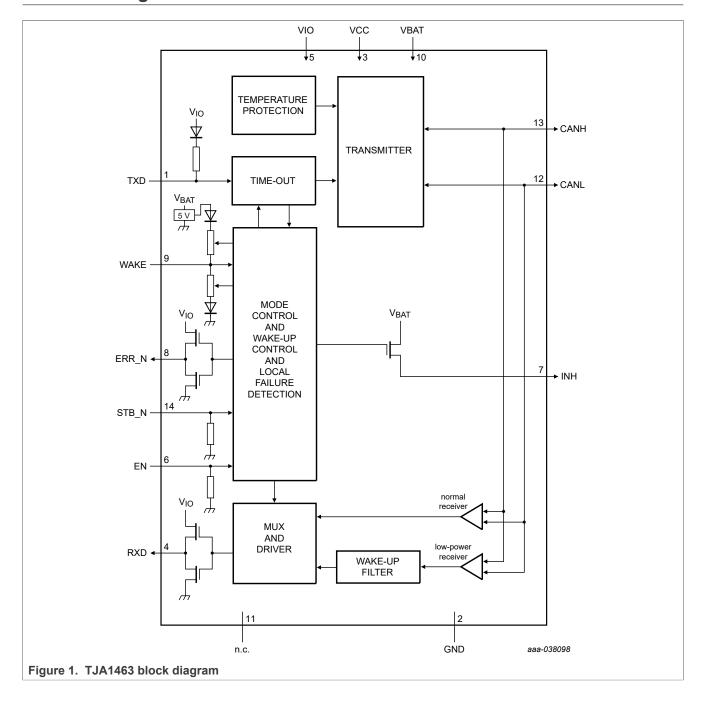
CAN FD Signal Improvement Capability (SIC) according to CiA 601-4:2019.

^[1] [2] [3] [4] [5] RXD is held LOW after wake-up request, enabling wake-up source recognition.

WUP = wake-up pattern according ISO11898-2:2016.
Only VBAT supply needed for wake-up.

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5 Block diagram

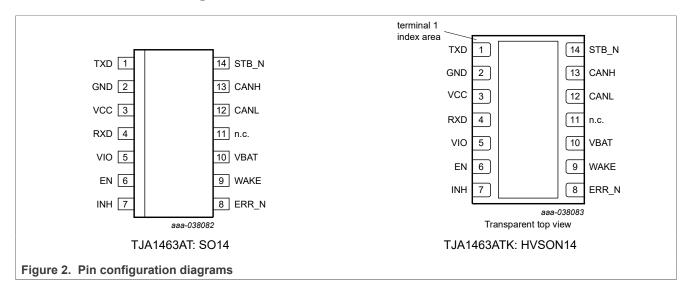


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Pinning information 6

6.1 Pinning



6.2 Pin description

Table 4. Pin description

Symbol	Pin	Type ^[1]	Description
TXD	1	I	transmit data input; inputs data (from the CAN controller) to be written to the bus lines
GND ^[2]	2	G	ground
VCC	3	Р	5 V supply voltage input
RXD	4	0	receive data output; outputs data read from the bus lines (to the CAN controller)
VIO	5	Р	supply voltage input for I/O level adapter
EN	6	I	enable control input
INH	7	AO	inhibit output for switching external voltage regulators
ERR_N	8	0	local failure detection; wake-up source recognition and power-on indication output (active-LOW)
WAKE	9	Al	local wake-up input
VBAT	10	Р	battery supply voltage input
n.c.	11	-	not connected
CANL	12	AIO	LOW-level CAN bus line
CANH	13	AIO	HIGH-level CAN bus line
STB_N	14	I	Standby mode control input (active-LOW)

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I: digital input; O: digital output; AI: analog input; AO: analog output; AIO: analog input/output; P: power supply; G: ground.
HVSON14 package die supply ground is connected to both the GND pin and the exposed center pad. The GND pin must be soldered to board ground.
For enhanced thermal and electrical performance, it is also recommended to solder the exposed center pad to board ground.

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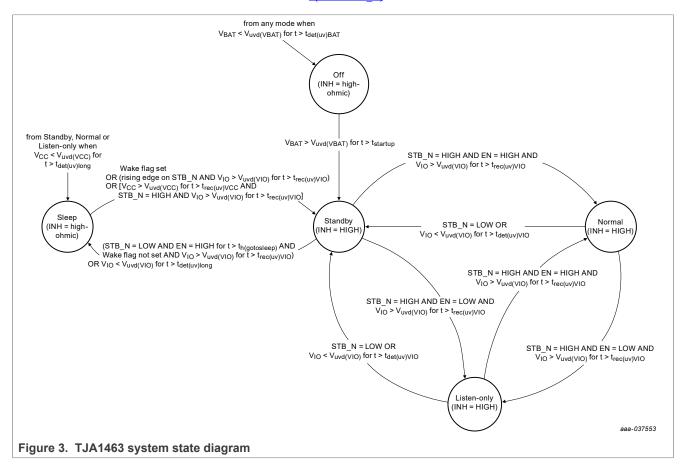
7 Functional description

7.1 Operating modes

The TJA1463 contains two independent state machines, a system state machine and a CAN state machine. Two state machines are needed to secure flag handling during undervoltage conditions. These state machines support a number of interdependent operating modes. The system state machine controls the CAN state machine, but both state machines are independently affected by the V_{CC} undervoltage status. For both state machines, undervoltage detection is defined as $V_x < V_{uvd(x)}$ for $t > t_{det(uv)}$ and undervoltage recovery is defined as $V_x > V_{uvd(x)}$ for $t > t_{rec(uv)}$.

7.1.1 System operating modes

The system state machine in the TJA1463 supports five system operating modes. Control pins STB_N and EN are used to select the operating mode. Figure 3 describes how to switch between operating modes. Mode changes are completed after transition time $\underline{t_{t(moch)}}$. Fail-safe diagnostic information, as described in Section 7.2, is available on pin ERR_N with a delay of $\underline{t_{d(moch-ERR\ N)}}$ after a mode change.



7.1.1.1 Off mode

The TJA1463 switches to Off mode from any mode mode when the battery voltage falls below the undervoltage detection threshold, $V_{uvd(VBAT)}$. The device starts up in Off mode

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when the battery is connected for the first time (cold start). Pins INH and ERR_N are in a high-ohmic state in Off mode.

7.1.1.2 Standby mode

Standby mode is the first-level power-saving mode of the TJA1463. When V_{BAT} rises above the undervoltage detection threshold, $V_{uvd(VBAT)}$, the TJA1463 starts to boot up, triggering an initialization procedure. It switches to Standby mode after $\underline{t_{startup}}$, resulting in a HIGH level on pin INH.

When V_{IO} rises above the undervoltage detection threshold, $V_{uvd(VIO)}$, the TJA1463 switches to Normal mode if pins STB_N and EN are HIGH, and to Listen-only mode if STB_N is HIGH and EN is LOW. It will remain in Standby mode if STB_N is LOW.

The TJA1463 will switch to Sleep mode if V_{IO} remains below $V_{uvd(VIO)}$ for $\underline{t}_{det(uv)long}$ and/or V_{CC} remains below $V_{uvd(VCC)}$ for $t_{det(uv)long}$. A transition from Standby mode to Sleep mode can also be triggered by holding STB_N LOW and EN HIGH for $\underline{t}_{h(gotosleep)}$ (also known as a 'go-to-sleep' command). This 'go-to-sleep' command is overruled if the Wake flag is set, in which case the device remains in Standby mode.

7.1.1.3 Normal mode

HIGH levels on pin STB_N and pin EN selects Normal mode, provided the battery supply voltage, V_{BAT} , and V_{IO} are present. Pin INH remains HIGH, so voltage regulators controlled by pin INH will also be active (see <u>Figure 12</u>).

7.1.1.4 Listen-only mode

A HIGH level on pin STB_N and a LOW level on pin EN selects Listen-only mode, provided V_{BAT} and V_{IO} are present. Pin INH remains HIGH, so voltage regulators controlled by pin INH will also be active.

In Listen-only mode the receiver is enabled, but the transmitter is disabled.

7.1.1.5 Sleep mode

Sleep mode is the second-level power-saving mode of the TJA1463. Sleep mode is entered in a number of ways:

- · via Standby mode, in response to a 'go-to-sleep' command
- via Standby mode as a result of a V_{IO} undervoltage longer than t_{det(uv)long}
- via all other modes, except Off mode, as a result of a V_{CC} undervoltage longer than
 t_{det(uv)long}

In Sleep mode, the transceiver behaves as described for Standby mode, with the exception that pin INH is set high-ohmic. Voltage regulators controlled by this pin are switched off and the current into pin VBAT is reduced to a minimum.

A number of events will cause the TJA1463 to exit Sleep mode, switching to Standby mode:

- · setting the Wake flag
- a rising edge on pin STB_N (if $V_{IO} > V_{uvd(VIO)}$)
- V_{CC} > V_{uvd(VCC)}, V_{IO} > V_{uvd(VIO)} and the 'go-to-sleep' command has not been activated. After entering Standby mode, the TJA1463 will enter Normal or Listen-Only if STB_N is HIGH.

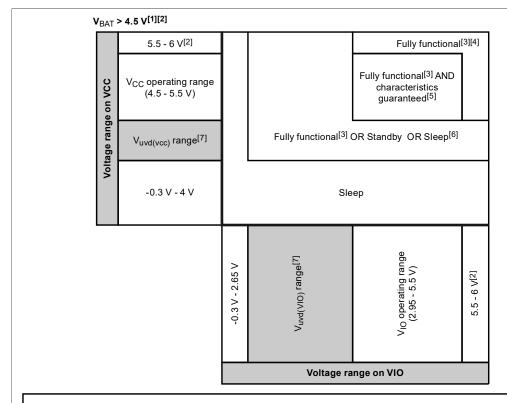
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7.1.1.6 System operating modes and gap-free operation

Gap-free operation guarantees defined behavior at all voltage levels. Supply voltage-to-operating mode mapping is detailed in <u>Figure 4</u>.



- [1] V_{BAT} operating range is 4.5 V 28 V and the undervoltage detection threshold range, V_{uvd(BAT)}, is 4 V 4.5 V. For V_{BAT} < 4 V, the device is in Off state. For 4 V ≤ V_{BAT} ≤ 4.5 V the device is either in Off state (if a V_{BAT} undervoltage has been triggered) or in the state as shown in this diagram (if a V_{BAT} undervoltage has not been triggered). For 28 V < V_{BAT} < 40 V this diagram applies, with the single exception that the datasheet characteristics are not guaranteed.
- [2] 6 V is the IEC 60134 Absolute Maximum Rating (AMR) for VCC and VIO, 40 V the AMR for VBAT (see Limiting values table). Above the AMR, irreversible changes in characteristics, functionality or performance may occur. Returning from above AMR to the operating range, datasheet characteristics and functionality cannot be guaranteed.
- [3] Target transceiver functionality as described in the datasheet is applicable.
- [4] Prolonged operation of the device outside the operating range may impact reliability over lifetime. Returning to the operating range, datasheet characteristics are guaranteed provided the AMR has not been exceeded.
- [5] Datasheet characteristics are guaranteed within the V_{BAT}, V_{CC} and V_{IO} operating ranges. Exceptions are described in the Static and Dynamic characteristics tables.
- [6] For a given value of V_{CC} and V_{IO}, a specific device will be in a single defined state, determined by its undervoltage detection thresholds V_{uvd(VCC)} and V_{uvd(VIO)}. The actual thresholds can vary between devices (within the ranges specified in this datasheet). To guarantee the device will be in a specific state, V_{CC} and V_{IO} must be either above the maximum or below the minimum thresholds specified for these undervoltage detection ranges.
- [7] The device is fully functional when both V_{CC} and V_{IO} are above the undervoltage threshold. If V_{CC} or V_{IO} is below the undervoltage threshold, the device will be in Standby or Sleep mode.

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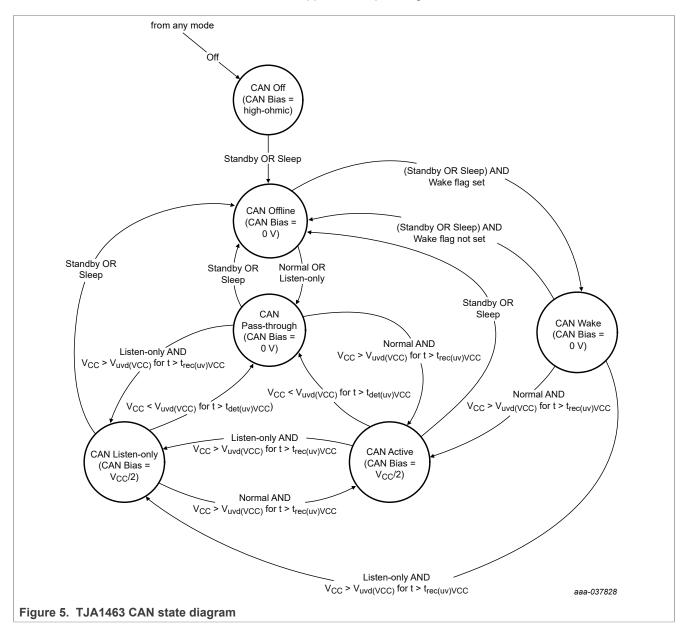
Figure 4. TJA1463 supply voltage ranges and gap-free operation

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7.1.2 CAN operating modes

The CAN state machine supports six operating modes.



7.1.2.1 CAN Off mode

When the TJA1463 system state machine is in Off mode, the CAN state machine will be in CAN Off mode, with the bus pins and pin RXD in a high-ohmic state.

7.1.2.2 CAN Offline mode

When the TJA1463 system state machine is in Sleep or Standby mode and the Wake flag has not been set, the CAN state machine will be in CAN Offline mode. The bus pins are biased to ground.

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The transceiver is unable to transmit or receive data and the low-power receiver is activated to monitor the bus for a wake-up pattern. Pin RXD is HIGH.

7.1.2.3 CAN Wake mode

When the TJA1463 system state machine is in Sleep or Standby mode and the wake flag has been set, the CAN state machine will be in CAN Wake mode. Pin RXD will be LOW, reflecting the active wake-up request. The bus pins are biased to ground.

7.1.2.4 CAN Pass-through mode

When the TJA1463 system state machine is in Normal or Listen-only mode and V_{CC} is below the undervoltage detection threshold, $V_{uvd(VCC)}$, the CAN state machine will be in CAN Pass-through mode.

The transceiver cannot transmit data via the bus lines in this mode. The output voltage on the bus pins is biased to ground. Differential data on the bus pins is converted to digital data via the low-power receiver and the results are output on pin RXD.

7.1.2.5 CAN Active mode

When the TJA1463 system state machine is in Normal mode and V_{CC} is above the undervoltage detection threshold, $V_{uvd(VCC)}$, the CAN state machine will be in CAN Active mode. The transceiver can transmit and receive data via bus lines CANH and CANL. Pin TXD must be HIGH at least once in CAN Active mode before the first transmission can begin. The differential receiver converts the analog data on the bus lines into digital data on pin RXD. In order to support high bit rates, especially in CAN FD systems, the Signal Improvement function largely eliminates topology-related reflections and impedance mismatches. In recessive state, the output voltage on the bus pins is $V_{CC}/2$.

7.1.2.6 CAN Listen-only mode

When the TJA1463 system state machine is in Listen-only mode and V_{CC} is above the undervoltage detection threshold, $V_{uvd(VCC)}$, the CAN state machine will be in CAN Listen-only mode. The transmitter is disabled. The differential receiver converts the analog data on the bus lines into digital data on pin RXD. As in CAN Active mode, the bus pins are biased to $V_{CC}/2$.

7.2 Internal flags

The device makes use of four internal flags for fail-safe fallback control and system diagnosis. These flags can be polled by the controller via pin ERR_N while V_{IO} is active. Which flag is available on pin ERR_N at any time depends on the current system operating mode; see <u>Table 5</u>.

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Table 5. Accessing internal flags via pin ERR_N

Internal flag	Flag available on pin ERR_N ^[1]	Flag status: set ^[2]	Flag status: not set ^[2]	Flag cleared
Pwon	in Listen-only mode (coming from Standby or Sleep mode)	V _{BAT} has risen above V _{uvd(VBAT)}	V_{BAT} has not risen above $V_{uvd(VBAT)}$	on entering Normal mode
Wake	in Standby and Sleep modes (provided V _{IO} and V _{BAT} are present)	remote or local wake-up detected OR Pwon flag has been set	no remote or local wake-up detected	on entering Normal mode
Wake-up source	in Normal mode	local wake-up OR Pwon flag has been set	remote wake-up OR no wake-up	on leaving Normal mode
Local failure	in Listen-only mode (coming from Normal mode)	on occurrence of: - TXD dominant failure OR - TXD-RXD short circuit OR - Bus dominant failure OR - Overtemperature	none of the set conditions have been met	when Pwon flag is set or, provided all local failures have been resolved, when: - device enters Normal mode OR - RXD dominant while TXD recessive OR - bus dominant failure resolved AND no other local failure has set the flag

^[1] Pin ERR_N is an active-LOW output; a LOW level indicates a set flag and a HIGH level indicates the flag has not been set.

7.2.1 Pwon flag

Pwon is the V_{BAT} power-on flag. This flag is set when the voltage on pin VBAT recovers after previously dropping below $V_{uvd(VBAT)}$ (usually because the battery was disconnected). The Pwon flag can be used for cold start diagnosis. The Wake and Wake-up source flags are set to ensure consistent system power-up under all supply conditions. Coming from Sleep or Standby and entering Listen-Only mode, a LOW level on pin ERR_N signals that the Pwon flag has been set. The flag is cleared when the transceiver enters Normal mode.

7.2.2 Wake flag

The Wake flag is set when the transceiver detects a local or remote wake-up request.

7.2.2.1 Local wake-up (via WAKE pin)

A local wake-up request is registered when the logic level on pin WAKE changes and the new level remains stable for at least \underline{t}_{wake} . The system state machine can set the Wake flag in Standby or Sleep mode. Setting the Wake flag clears the timers. Once set, the Wake flag status is immediately available on pins ERR_N and RXD (provided V_{IO} and V_{BAT} are present). This flag is also set at power-on and cleared when the transceiver enters Normal mode.

7.2.2.2 Remote wake-up (via the CAN bus)

The TJA1463 wakes up from Sleep to Standby mode when a dedicated wake-up pattern (specified in ISO 11898-2: 2016) is detected on the bus.

The wake-up pattern consists of:

- a dominant phase of at least twake(busdom) followed by
- a recessive phase of at least twake(busrec) followed by
- a dominant phase of at least twake(busdom)

Dominant or recessive bits between the above mentioned phases that are shorter than $t_{wake(busdom)}$ and $t_{wake(busrec)}$ respectively are ignored.

The complete dominant-recessive-dominant pattern must be received within $\underline{t}_{to(wake)bus}$ to be recognized as a valid wake-up pattern (see Figure 6). Otherwise, the internal wake-

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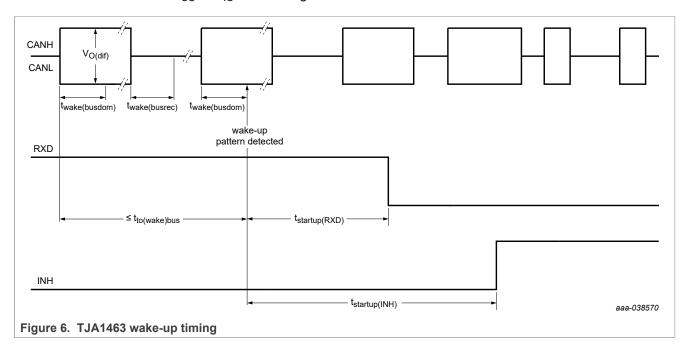
^[2] Status since flag was last cleared.

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up logic is reset. The complete wake-up pattern then needs to be retransmitted to trigger a wake-up event. Pins RXD and ERR_N remain HIGH until the wake-up event has been triggered and then switch LOW after $\underline{t}_{startup(RXD)}$. Pin INH remains floating until the wake-up event has been triggered and then switches HIGH after $\underline{t}_{startup(INH)}$.

A wake-up event is not flagged on RXD if any of the following events occurs while a valid wake-up pattern is being received:

- The device switches to Normal mode
- ullet The complete wake-up pattern was not received within $t_{to(wake)bus}$
- A V_{CC} or V_{IO} undervoltage is detected



7.2.3 Wake-up source flag

Wake-up source recognition is provided via the Wake-up source flag. It is set after the Wake flag has been set by a local wake-up request via the WAKE pin. The Wake-up source flag can be polled via the ERR_N pin in Normal mode (see <u>Table 5</u>). This flag is also set at power-on and cleared when the transceiver leaves Normal mode.

7.2.4 Local failure flag

In Normal and Listen-only modes, the transceiver can distinguish four local failure events, any of which will cause the Local failure flag to be set. The four local failure events are:

- · TXD dominant failures
- TXD-to-RXD short circuit
- Bus dominant failures
- Overtemperature

The nature and detection of these local failures is described in <u>Section 7.3</u>. The Local failure flag can be polled via the ERR_N pin in Listen-only mode, when coming from Normal mode (see <u>Table 5</u>).

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This flag is cleared at power-on when the Pwon flag is set or, provided all local failures have been resolved, when:

- · The device enters Normal mode OR
- · RXD is dominant while TXD is recessive OR
- · Bus dominant failure has been resolved AND no other local failure has set the flag

7.3 Local failure events

The TJA1463 can detect four different local failure conditions, any of which will set the Local failure flag. In most cases, the transmitter is disabled.

7.3.1 TXD dominant failures

A hardware and/or software application failure that caused pin TXD to be held LOW would drive the bus lines to a permanent dominant state (blocking all network communications). The TXD dominant time-out function prevents such a network lock-up. A 'TXD dominant time-out' timer is started when pin TXD goes LOW. If the LOW state on this pin persists for longer than $\underline{t}_{to(dom)TXD}$, the transmitter is disabled, releasing the bus lines to recessive state. The transmitter remains disabled until the Local failure flag has been cleared. The TXD dominant time-out timer is reset when pin TXD is set HIGH.

7.3.2 TXD-to-RXD short circuit

A short-circuit between pins RXD and TXD would lock the bus in a permanent dominant state once it had been driven dominant, because the low-side driver of RXD is typically stronger than the high-side driver of the controller connected to TXD. TXD-to-RXD short-circuit detection prevents such a network lock-up by disabling the transmitter. The transmitter remains disabled until the Local failure flag has been cleared.

7.3.3 Bus dominant failures

A CAN bus short circuit (to V_{BAT} , V_{CC} or GND) or a failure in one of the other network nodes could result in a differential voltage on the bus high enough to represent a bus dominant state. Because a node will not begin to transmit while the bus is dominant, the host controller would not be able to detect this failure condition. However, bus dominant clamping detection will detect the short circuit. The Local failure flag is set if the dominant state on the bus persists for longer than $\underline{t}_{to(dom)bus}$. By checking this flag, the controller can determine if a clamped bus is blocking network communications. There is no need to disable the transmitter. Note that the Local failure flag is reset as soon as the bus returns to recessive state.

7.3.4 Overtemperature

The device is protected against overtemperature conditions. If the junction temperature exceeds the shutdown junction temperature, $T_{j(sd)}$, the CAN bus drivers are disabled. The transmitter will remain disabled until the junction temperature drops below $T_{j(sd)rel}$ and the Local failure flag has been cleared.

7.4 I/O levels

Pin VIO should be connected to the same supply voltage used to supply the microcontroller. This adjusts the signal levels on pins TXD, RXD, STB_N, EN and

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ERR_N to the I/O levels of the microcontroller, allowing for direct interfacing without additional glue logic. Spurious signals from the microcontroller on pins STB_N and EN are filtered out with a filter time of $\underline{t}_{fitr(IO)}$.

7.5 WAKE pin

A local wake-up event is triggered by a LOW-to-HIGH or HIGH-to-LOW transition on the WAKE pin when V_{WAKE} passes the wake-up threshold, $V_{th(wake)}$. After the transition, the new HIGH or LOW level should remain stable for at least t_{wake} . This allows for maximum flexibility when designing a local wake-up circuit.

A local wake-up is guaranteed in the case of:

- a LOW-to-HIGH transition from $V_{WAKE} < V_{th(wake)min}$ to $V_{WAKE} > V_{th(wake)max}$, followed by $V_{WAKE} > V_{th(wake)max}$ for t > $t_{wake(max)}$
- a HIGH-to-LOW transition from $V_{WAKE} > V_{th(wake)max}$ to $V_{WAKE} < V_{th(wake)min}$, followed by $V_{WAKE} < V_{th(wake)min}$ for $t > t_{wake(max)}$

A local wake-up is guaranteed not to occur if the HIGH/LOW level after the transition does not remain stable for at least $t_{(wake)min}$.

To minimize current consumption, the internal bias voltage follows the logic state on the pin after a delay of t_{wake} . A HIGH level on pin WAKE is followed by an internal pull-up to V_{BAT} . A LOW level on pin WAKE is followed by an internal pull-down towards GND. In applications that do not make use of the local wake-up facility, it is recommended to connect the WAKE pin to pin VBAT or GND for optimal EMI performance.

7.6 Internal biasing of TXD, STB N and EN input pins

Pin TXD has an internal pull-up to V_{IO} and pins STB_N and EN have internal pull-downs to GND to ensure a safe, defined state in case one, or all, of these pins is left floating. Pull-up/pull-down resistors are present on these pins in all states. Pull-down on pin EN is only active when V_{BAT} is present.

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Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134); all voltages are referenced to pin GND, unless otherwise specified; positive currents flow into the IC.

Symbol	Parameter	Conditions		Min	Max	Unit
V _x	Voltage on pin x ^[1]	pins VCC, VIO, TXD, STB_N, EN		-0.3	+6	V
				-	+7 ^[2]	V
		pin VBAT, load dump		-0.3	+40 ^[3]	V
		pin INH		-0.3	V _{BAT} +0.3 ^[4]	V
		pins CANH, CANL, WAKE		-36	+40	V
		pins RXD, ERR_N		-0.3	V _{IO} +0.3 ^[5]	V
I _{O(INH)}	output current on pin INH			-2	-	mA
V _(CANH-CANL)	voltage between pin CANH and pin CANL			-40	+40	V
V _{trt}	transient voltage	on pins VBAT, WAKE, CANH, CANL	[6]			
		pulse 1		-100	-	V
		pulse 2a		-	+75	V
		pulse 3a		-150	-	٧
		pulse 3b		-	+100	V
V _{ESD}	electrostatic discharge	IEC 61000-4-2 (150 pF, 330 Ω discharge circuit)	[7]			
	voltage	on pins CANH, CANL		-6	+6	kV
		on pin VBAT with 100 nF capacitor; pin WAKE with 33 kΩ resistor		-8	+8	kV
		Human Body Model (HBM)				
		on any pin	[8]	-4	+4	kV
		on pins CANH, CANL	[9]	-8	+8	kV
		Charged Device Model (CDM)	[10]			
ı		on corner pins		-750	+750	V
		on any other pin		-500	+500	٧
T_{vj}	virtual junction temperature		[11]	-40	+150	°C
T _{stg}	storage temperature		[12]	-55	+150	°C

- The device can sustain voltages up to the specified values over the product lifetime, provided applied voltages (including transients) never exceed these
- The device can withstand voltages between 6 V and 7 V for a total of 20 s over the product lifetime.
- For a maximum of 50 hours over the product lifetime.
- Absolute maximum of 40 V under the conditions defined in Table note 3 above.
- Subject to the qualifications detailed in Table notes 1 and 2 above for pins VCC, VIO, TXD, STB_N and EN.

 Verified by an external test house according to IEC TS 62228, Section 4.2.4; parameters for standard pulses defined in ISO 7637, Part 2.
- Verified by an external test house according to IEC TS 62228, Section 4.3. [7]
- According to AEC-Q100-002.
- Pins stressed to reference group containing all ground and supply pins, emulating the application circuit (Figure 12). HBM pulse as specified in AEC-Q100-002 used
- [10] According to AEC-Q100-011.
- [11] In accordance with IEC 60747-1. An alternative definition of virtual junction temperature is: T_{vj} = T_{amb} + P × R_{th(j-a)}, where R_{th(j-a)} is a fixed value used in the calculation of T_{vj}. The rating for T_{vj} limits the allowable combinations of power dissipation (P) and ambient temperature (T_{amb}).
 [12] T_{stg} in application according to IEC61360-4. For component transport and storage conditions, see instead IEC61760-2.

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CAN FD signal improvement transceiver with Sleep mode

Thermal characteristics

Table 7. Thermal characteristics

Value determined for free convection conditions on a JEDEC 2S2P board.

Symbol	Parameter	Conditions ^[1]	Тур	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	SO14	74	K/W
		HVSON14	46	K/W
R _{th(j-c)}	thermal resistance from junction to case ^[2]	HVSON14	13	K/W
$\Psi_{j\text{-top}}$	thermal characterization parameter from junction to top of package	SO14	13	K/W
		HVSON14	7	K/W

According to JEDEC JESD51-2, JESD51-5 and JESD51-7 at natural convection on 2s2p board. Board with two inner copper layers (thickness: 35 µm) and thermal via array under the exposed pad connected to the first inner copper layer (thickness: 70 µm). Case temperature refers to the center of the heatsink at the bottom of the package.

10 Static characteristics

Table 8. Static characteristics

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC. [1]

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply; pi	n VCC			'		
V _{CC}	supply voltage		4.5	-	5.5	V
V_{uvd}	undervoltage detection voltage		[2] 4	-	4.5	V
V _{uvhys}	undervoltage hysteresis voltage		50	-	-	mV
I _{CC}	supply current	Normal mode				
		dominant; $V_{TXD} = 0 \text{ V}$; $t < t_{to(dom)TXD}$	-	42	70	mA
		dominant; V _{TXD} = 0 V; short circuit on bus lines; -3 V < (V _{CANH} = V _{CANL}) < +40 V	-	-	125	mA
		Normal mode, recessive; V _{TXD} = V _{IO}	-	7	10	mA
		Listen-only mode	-	5	8	mA
		Standby or Sleep mode; T _{vj} < 85 °C	-	-	2	μA
I/O level a	dapter supply; pin VIO			·		
V _{IO}	supply voltage		2.95	5 -	5.5	V
V_{uvd}	undervoltage detection voltage		2.6	5 -	2.95	V
V _{uvhys}	undervoltage hysteresis voltage		50	-	-	mV
I _{IO}	supply current	Normal mode, dominant; V _{TXD} = 0 V	-	90	250	μA
		Normal mode, recessive, $V_{TXD} = V_{IO}$ or Listen-only mode	-	-	3	μΑ

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Table 8. Static characteristics...continued

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC. [1]

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Standby or Sleep mode; T _{vj} < 85 °C	-	-	2	μA
Supply; pir	VBAT					
V _{BAT}	battery supply voltage		4.5	-	28	V
V _{uvd}	undervoltage detection voltage		2] 4	-	4.5	V
I _{BAT}	battery supply current	Normal or Listen-only mode; pin INH left open	-	80	300	μA
		Normal or Listen-only mode; pin INH left open; $T_{vj} \le 25 \text{ °C}$; $V_{BAT} = 14.5 \text{ V}$	-	80	100	μA
		Standby mode; pin INH left open; $V_{WAKE} = V_{BAT}$; $T_{vj} < 85 ^{\circ}C$	-	13	26	μΑ
		Sleep mode; V _{WAKE} = V _{BAT} ; T _{vj} < 85 °C	-	13	26	μA
CAN trans	mit data input; pin TXD					
V _{IH}	HIGH-level input voltage		0.7V _I	o -	-	V
V _{IL}	LOW-level input voltage		-	-	0.3V _{IO}	V
$V_{hys(TXD)}$	hysteresis voltage on pin TXD		50	-	-	mV
R _{pu}	pull-up resistance		20	-	80	kΩ
C _i	input capacitance		3] _	-	10	pF
CAN recei	ve data output; pin RXD		·			
I _{OH}	HIGH-level output current	V _{RXD} = V _{IO} - 0.4 V	-10	-	-1	mA
I _{OL}	LOW-level output current	V _{RXD} = 0.4 V	1	-	10	mA
Standby a	nd enable control inputs; pins	STB_N and EN				
V _{IH}	HIGH-level input voltage		0.7V _I	o -	-	V
V _{IL}	LOW-level input voltage		-	-	0.3V _{IO}	V
V _{hys}	hysteresis voltage		50	-	-	mV
R _{pd}	pull-down resistance		^{4]} 20	-	80	kΩ
C _i	input capacitance		3] -	-	10	pF
Local failur	re detection and power-on indi	cation output; pin ERR_N				
I _{OH}	HIGH-level output current	$V_{ERR_N} = V_{IO} - 0.4 V$	-50	-	-4	μA
I _{OL}	LOW-level output current	V _{ERR_N} = 0.4 V	0.1	-	2	mA
Local wake	e-up input; pin WAKE		·	,	*	,
R _{pu}	pull-up resistance	$V_{\text{WAKE}} > V_{\text{th(wake)(max)}}$ for $t > t_{\text{wake(max)}}$	100	-	400	kΩ
R _{pd}	pull-down resistance	$V_{\text{WAKE}} < V_{\text{th(wake)(min)}}$ for t > t _{wake(max)}	100	-	400	kΩ
V _{th(wake)}	wake-up threshold voltage	Sleep or Standby mode	1.8	-	2.6	V
V _{hys}	hysteresis voltage		90	-	-	mV

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Table 8. Static characteristics...continued

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC. [1]

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Inhibit outp	put; pin INH						
ΔV_H	HIGH-level voltage drop	$\Delta V_H = V_{BAT} - V_{INH}$; $I_{INH} = -1$ mA		0	-	1	V
		$\Delta V_H = V_{BAT} - V_{INH}$; $I_{INH} = -2 \text{ mA}$		0	-	2	V
IL	leakage current	Sleep mode; Off mode		- 2	-	+2	μA
I _{O(sc)}	short-circuit output current	V _{INH} = 0 V		-15	-	-	mA
	pins CANH and CANL						
$V_{O(dom)}$	dominant output voltage	V_{TXD} = 0 V; t < $t_{to(dom)TXD}$; V_{CC} = 4.75 V to 5.25 V					
		pin CANH; R _L = 50 Ω to 65 Ω		2.89	3.5	4.26	V
		pin CANL; R_L = 50 Ω to 65 Ω		0.77	1.5	2.13	V
V _{TXsym}	transmitter voltage symmetry	VIXSVM VI.ANH VI.ANH, OSPIII III,	[3] [5]	0.9V _{CC}	-	1.1V _{CC}	V
V _{cm(step)}	common mode voltage step		[3] [5] [6]	-150	-	+150	mV
$V_{cm(p-p)}$	peak-to-peak common mode voltage		[3] [5] [6]	-300	-	+300	mV
$V_{O(dif)}$	differential output voltage	dominant; Normal mode; $V_{TXD} = 0 \text{ V}$; $t < t_{to(dom)TXD}$; $V_{CC} = 4.75 \text{ V}$ to 5.25 V	[5]				
		$R_L = 50 \Omega$ to 65Ω		1.5	-	2.75	V
		R_L = 45 Ω to 70 Ω		1.4	-	3.3	V
		R _L = 2240 Ω	[3]	1.5	-	5	V
		recessive; no load					
		Normal or Listen-only mode; $V_{TXD} = V_{IO}$		-50	-	+50	mV
		Standby or Sleep mode		-0.2	-	+0.2	V
V _{O(rec)}	recessive output voltage	Normal or Listen-only mode; $V_{TXD} = V_{IO}$; no load		2	2.5	3	V
		Standby or Sleep mode; no load		-0.1	0	+0.1	V
$V_{th(RX)dif}$	differential receiver threshold voltage	-12 V ≤ V _{CANH} ≤ +12 V; -12 V ≤ V _{CANL} ≤ +12 V					
		Normal or Listen-only mode		0.5	-	0.9	V
		Standby or Sleep mode		0.4	-	1.1	V
V _{rec(RX)}	receiver recessive voltage	-12 V ≤ V _{CANH} ≤ +12 V; -12 V ≤ V _{CANL} ≤ +12 V					
		Normal or Listen-only mode		-4	-	+0.5	V
		Standby or Sleep mode		-4	-	+0.4	V
$V_{\text{dom}(RX)}$	receiver dominant voltage	-12 V ≤ V _{CANH} ≤ +12 V; -12 V ≤ V _{CANL} ≤ +12 V					

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Table 8. Static characteristics...continued

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC. [1]

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Normal or Listen-only mode	0.9	-	9	V
		Standby or Sleep mode	1.1	-	9	V
V _{hys(RX)dif}	differential receiver hysteresis voltage	-12 V ≤ V _{CANH} ≤ +12 V; -12 V ≤ V _{CANL} ≤ +12 V; Normal or Listen- only mode	100	-	-	mV
I _{O(sc)}	short-circuit output current	-15 V ≤ V _{CANH} ≤ +40 V; -15 V ≤ V _{CANL} ≤ +40 V	-	-	115	mA
I _{O(sc)rec}	recessive short-circuit output current	$ \begin{array}{l} -27 \text{ V} \leq \text{V}_{\text{CANH}} \leq +32 \text{ V}; \\ -27 \text{ V} \leq \text{V}_{\text{CANL}} \leq +32 \text{ V}; \\ \text{Normal or Listen-only mode;} \\ \text{V}_{\text{TXD}} = \text{V}_{\text{IO}} \text{ for } t > t_{\text{d(TXD-busrec)end}} \end{array} $	-3	-	+3	mA
IL	leakage current	$V_{CC} = V_{IO} = 0 \text{ V or pins shorted to GND via}$ 47 K Ω ; $V_{CANH} = V_{CANL} = 5 \text{ V}$;	-10	-	+10	μA
R _i	input resistance	$-2 \text{ V} \le \text{V}_{CANL} \le +7 \text{ V}; -2 \text{ V} \le \text{V}_{CANH} \le +7 \text{ V}$	25	40	50	kΩ
ΔR _i	input resistance deviation	$0 \text{ V} \le \text{V}_{CANL} \le +5 \text{ V}; 0 \text{ V} \le \text{V}_{CANH} \le +5 \text{ V}$	-3	-	+3	%
R _{i(dif)}	differential input resistance	$-2 \text{ V} \le \text{V}_{CANL} \le +7 \text{ V}; -2 \text{ V} \le \text{V}_{CANH} \le +7 \text{ V}$	50	80	100	kΩ
C _{i(cm)}	common-mode input capacitance	[3]	-	-	30	pF
C _{i(dif)}	differential input capacitance	[3]	-	-	15	pF
Signal Impr	ovement function on CANH or	CANL; $+4.75 \text{ V} \le \text{V}_{CC} \le +5.25 \text{ V}$; see Figure 10	and Fig	ure 11		
$R_{i(dom)}$	dominant phase input resistance	bus dominant; V_{CC} - 1.6 V \leq V_{CANH} \leq V_{CC} - 1.2 V;	-	-	30	Ω
$R_{i(dif)dom}$	dominant phase differential input resistance	+1.2 V \leq V _{CANL} \leq +1.6 V; $R_{i(dif)dom} = R_{i(dom)CANH} + R_{i(dom)CANL}$	-	-	60	Ω
R _{i(extdom)}	extended dominant phase input resistance ^[8]	bus dominant-to-recessive transition; +2.3 V \leq V _{CANH} \leq V _{CC} -2.3 V;	-	-	25	Ω
R _{i(dif)extdom}	extended dominant phase differential input resistance ^[8]	+2.3 V \leq V _{CANL} \leq V _{CC} - 2.3 V; R _{i(dif)extdom} = R _{i(extdom)CANH} + R _{i(extdom)CANL}	-	-	50	Ω
R _{i(actrec)}	active recessive phase input resistance ^[8]	bus dominant-to-recessive transition; +1.5 V \leq V _{CANH} \leq V _{CC} - 1.5 V;	37.5	-	62.5	Ω
R _{i(dif)actrec}	active recessive phase differential input resistance ^[8]	+1.5 V \leq V _{CANL} \leq V _{CC} - 1.5 V; R _{i(dif)actrec} = R _{i(actrec)CANH} + R _{i(actrec)CANL}	75	-	125	Ω
Temperatur	e detection					
T _{j(sd)}	shutdown junction temperature	[3]	180	-	200	°C
T _{j(sd)rel}	release shutdown junction temperature	[3]	175	-	195	°C

^[1] All parameters are guaranteed over the junction temperature range by design. Factory testing uses correlated test conditions to cover the specified

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temperature and power supply voltage ranges.
Undervoltage is detected between min and max values. Undervoltage is guaranteed to be detected below min value and guaranteed not to be detected above max value.

Not tested in production; guaranteed by design.

Pull-down on EN pin is only active when V_{BAT} is present. [4]

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- [5] The test circuit used to measure the bus output voltage symmetry and the common-mode voltages (which includes C_{SPLIT}) is shown in Figure 14.
- [6] See Figure 9
- This parameter is defined in CiA specification CiA 601-4:2019 as t_{SIC_TX_base} and is specified in the Dynamic Characteristics table (see <u>Table 9</u> and Figure 10).
- [8] Extended dominant and active recessive phases are not DC states and are only valid for a limited time after a dominant-to-recessive transition on pin TXD.

11 Dynamic characteristics

Table 9. Dynamic characteristics

 T_{Vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground. [1]

Parameter	Conditions		Min	Тур	Max	Unit
naracteristics; V_{CC} = 4.75 V to 5.25 V; $t_{bit(TX)}$	_{D)} ≥ 125 ns; see <u>Figure 7</u> , <u>Figure 8</u>	, <u>Fig</u>	gure 10), <mark>Figur</mark>	<u>e 11</u> and	I
delay time from TXD to bus dominant	Normal mode		-	-	80	ns
delay time from TXD to bus recessive	Normal mode		-	-	80	ns
delay time from bus dominant to RXD	Normal or Listen-Only mode		-	-	110	ns
delay time from bus recessive to RXD	Normal or Listen-Only mode		-	-	110	ns
delay time from TXD LOW to RXD LOW	Normal mode		-	-	190	ns
	Normal mode; V _{CC} = 4.5 V to 5.5 V		-	-	255	ns
delay time from TXD HIGH to RXD HIGH	Normal mode		-	-	190	ns
	Normal mode; V _{CC} = 4.5 V to 5.5 V		-	-	255	ns
delay time from TXD to bus recessive end	Normal mode	[2] [3]	415	-	530	ns
delay time from TXD to bus dominant end	Normal mode	[2]	-	-	115	ns
delay time from TXD to extended bus dominant end	Normal mode	[2]	55	-	-	ns
delay time from TXD to bus active recessive start	Normal mode	[2]	70	-	120	ns
delay time from TXD to active recessive end	Normal mode	[2]	335	-	480	ns
g characteristics according to CiA 601-4:20	19; V_{CC} = 4.75 V to 5.25 V; $t_{bit(TXD)}$) ≥ 1	25 ns;	see Fig	gure 8 a	nd
transmitted recessive bit width deviation	$\Delta t_{bit(bus)} = t_{bit(bus)} - t_{bit(TXD)}$		-10	-	+10	ns
receiver timing symmetry	$\Delta t_{rec} = t_{bit(RXD)} - t_{bit(bus)}$		-20	-	+15	ns
received recessive bit width deviation	$\Delta t_{\text{bit}(RXD)} = t_{\text{bit}(RXD)} - t_{\text{bit}(TXD)}$		-30	-	+20	ns
g characteristics according to ISO 11898-2:	2016 ^[5] ; see <u>Figure 8</u> and <u>Figure 1</u>	3 ^[4]				,
transmitted recessive bit width	2 Mbit/s (t _{bit(TXD)} = 500 ns)					
	V _{CC} = 4.75 V to 5.25 V		490	-	510	ns
	V _{CC} = 4.5 V to 5.5 V		435	-	530	ns
	5 Mbit/s (t _{bit(TXD)} = 200 ns)					
	delay time from TXD to bus dominant delay time from bus dominant to RXD delay time from bus dominant to RXD delay time from bus recessive to RXD delay time from TXD LOW to RXD LOW delay time from TXD HIGH to RXD HIGH delay time from TXD to bus recessive end delay time from TXD to bus dominant end delay time from TXD to extended bus dominant end delay time from TXD to bus active recessive start delay time from TXD to active recessive end g characteristics according to CiA 601-4:20 transmitted recessive bit width deviation receiver timing symmetry received recessive bit width deviation g characteristics according to ISO 11898-2:	delay time from TXD to bus dominant delay time from TXD to bus recessive Normal mode delay time from Dus dominant to RXD Normal or Listen-Only mode delay time from bus dominant to RXD Normal or Listen-Only mode delay time from Dus recessive to RXD Normal or Listen-Only mode delay time from TXD LOW to RXD LOW Normal mode; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD HIGH to RXD HIGH Normal mode Normal mode; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD to bus recessive Normal mode delay time from TXD to bus dominant end delay time from TXD to bus dominant end delay time from TXD to extended bus dominant end delay time from TXD to active recessive Normal mode g characteristics according to CiA 601-4:2019; $V_{CC} = 4.75 \text{ V to } 5.25 \text{ V}$; $t_{bit(TXD)}$ transmitted recessive bit width deviation $\Delta t_{bit(RXD)} = t_{bit(RXD)} - t_{bit(TXD)}$ g characteristics according to ISO 11898-2:2016 ^[5] ; see Figure 8 and Figure 1 transmitted recessive bit width $V_{CC} = 4.75 \text{ V to } 5.25 \text{ V}$ $V_{CC} = 4.75 \text{ V to } 5.25 \text{ V}$	delay time from TXD to bus dominant delay time from TXD to Dus to RXD LOW delay time from TXD to bus recessive to RXD delay time from TXD to bus recessive to RXD delay time from TXD LOW to RXD LOW delay time from TXD to bus recessive to RXD delay time from TXD HIGH to RXD HIGH Normal mode $\frac{1}{\sqrt{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD to bus recessive to RXD Mormal mode $\frac{1}{\sqrt{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD to bus recessive end $\frac{1}{\sqrt{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD to bus recessive end $\frac{1}{\sqrt{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD to bus dominant end $\frac{1}{\sqrt{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ delay time from TXD to bus active recessive start delay time from TXD to active recessive end $\frac{1}{\sqrt{CC}} = 4.75 \text{ V to } 5.25 \text{ V}$; $t_{\text{bit}(TXD)} \ge 1$ transmitted recessive bit width deviation $\frac{1}{\sqrt{CC}} = 4.75 \text{ V to } 5.25 \text{ V}$; $t_{\text{bit}(TXD)} = 1 \text{ transmitted recessive bit width deviation}$ g characteristics according to ISO 11898-2:2016 ^[5] ; see Figure 8 and Figure 13 [4] transmitted recessive bit width $\frac{1}{\sqrt{CC}} = 4.75 \text{ V to } 5.25 \text{ V}$ $\frac{1}{\sqrt{CC}} = 4.75 \text{ V to } 5.25 \text{ V}$ $\frac{1}{\sqrt{CC}} = 4.75 \text{ V to } 5.25 \text{ V}$	delay time from TXD to bus recessive end elay time from TXD to bus recessive Normal mode - delay time from TXD to bus recessive Normal or Listen-Only mode - delay time from bus recessive to RXD Normal or Listen-Only mode - delay time from TXD LOW to RXD LOW Normal or Listen-Only mode - delay time from TXD LOW to RXD LOW Normal mode - Normal mode; - Normal mode; - Normal mode - Normal mode - Normal mode - Normal mode; - Normal mode - Normal mode - Normal mode - Normal mode -	aracteristics; $V_{CC} = 4.75 \text{ V}$ to 5.25 V ; $t_{bil(TXD)} \ge 125 \text{ ns}$; see Figure 7, Figure 8, Figure 10, Figure 8 delay time from TXD to bus dominant Normal mode	delay time from TXD to bus dominant of the total properties of the total prop

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CAN FD signal improvement transceiver with Sleep mode

Table 9. Dynamic characteristics...continued

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground. [1]

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
		V _{CC} = 4.75 V to 5.25 V		190	-	210	ns
		V _{CC} = 4.5 V to 5.5 V	[7]	170	-	230	ns
		8 Mbit/s (t _{bit(TXD)} = 125 ns)					
		V _{CC} = 4.75 V to 5.25 V		115	-	135	ns
Δt _{rec}	receiver timing symmetry	V _{CC} = 4.75 V to 5.25 V; for 2 Mbit/s, 5 Mbit/s and 8 Mbit/s		-20	-	+15	ns
		V _{CC} = 4.5 V to 5.5 V; 2 MBit/s		-65	-	+40	ns
		V _{CC} = 4.5 V to 5.5 V; 5 Mbit/s		-45	-	+15	ns
t _{bit(RXD)} ^[8]	bit time on pin RXD	2 Mbit/s ($t_{bit(TXD)}$ = 500 ns)					
		V _{CC} = 4.75 V to 5.25 V		470	-	520	ns
		V _{CC} = 4.5 V to 5.5 V		400	-	550	ns
		5 Mbit/s (t _{bit(TXD)} = 200 ns)					
		V _{CC} = 4.75 V to 5.25 V		170	-	220	ns
		V _{CC} = 4.5 V to 5.5 V	[7]	150	-	240	ns
		8 Mbit/s (t _{bit(TXD)} = 125 ns)					
		V _{CC} = 4.75 V to 5.25 V		95	-	145	ns
Dominant tim	e-out times					'	,
to(dom)TXD	TXD dominant time-out time	V _{TXD} = 0 V; Normal mode	[2] [9]	8.0	-	9	ms
to(dom)bus	bus dominant time-out time	V _{O(dif)} > 0.9 V; Normal or Listen- Only mode	[2] [9]	8.0	-	9	ms
Bus wake-up	times; pins CANH and CANL; see Fi	gure 6					
twake(busdom)	bus dominant wake-up time	Standby or Sleep mode	[2] [10]	0.5	-	1.8	μs
twake(busrec)	bus recessive wake-up time	Standby or Sleep mode	[2] [10]	0.5	-	1.8	μs
t _{to(wake)bus}	bus wake-up time-out time	Standby or Sleep mode	[2] [9]	8.0	-	9	ms
Mode transiti	ons	,				'	
t(moch)	mode change transition time		[2]	-	-	50	μs
startup	start-up time		[2]	-	-	1.5	ms
startup(RXD)	RXD start-up time	after local or remote wake-up detected	[2] [11]	4	-	20	μs
startup(INH)	INH start-up time	after local or remote wake-up detected; transition from Sleep to Standby	[2] [12]	4	-	50	μs
h(gotosleep)	go-to-sleep hold time	STB_N = LOW and EN = HIGH hold time for entering Sleep mode	[2] [13]	24	-	50	μs

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Table 9. Dynamic characteristics...continued

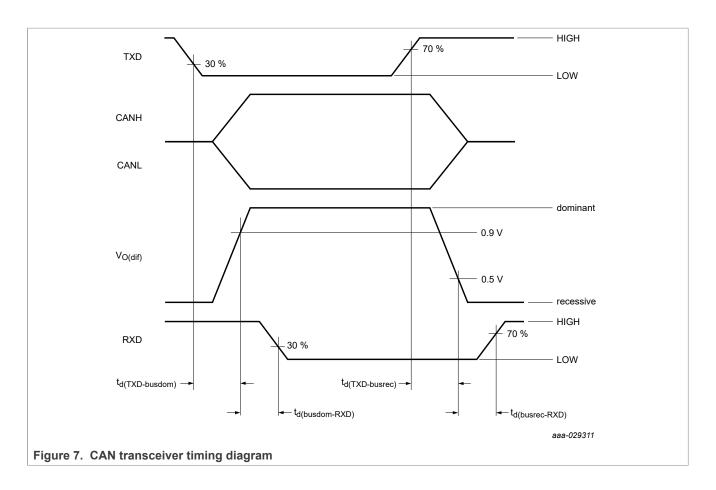
 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V; V_{BAT} = 4.5 V to 28 V; R_L = 60 Ω unless specified otherwise; all voltages are defined with respect to ground. [1]

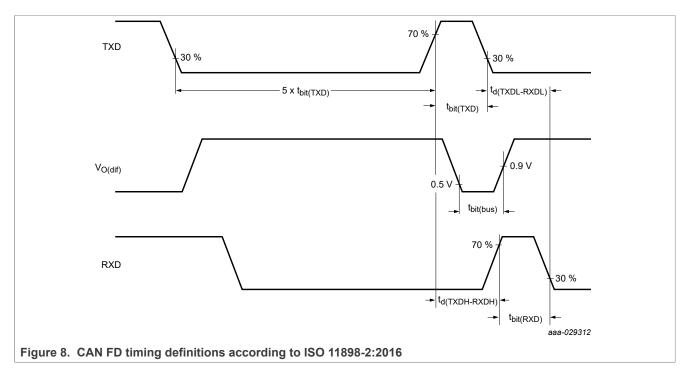
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
td(moch-ERR_N)	delay time from mode change to ERR_N	to ERR_N stable in response to a mode transition	[2]	-	_	20	μs
Local wake-up	input; pin WAKE						
<u>t</u> wake	wake-up time	in response to a falling or rising edge on pin WAKE; Standby or Sleep mode	[14]	20	-	50	μs
IO filter; pins S	STB_N, EN						
t _{fitr(IO)}	I/O filter time		[15]	1	-	5	μs
Undervoltage	detection; see <u>Figure 3</u> and <u>Figure 5</u>						
t _{det(uv)}	undervoltage detection time	on pin VBAT	[2]	-	-	30	μs
		on pin VCC	[2]	-	-	30	μs
		on pin VIO	[2]	-	-	30	μs
t_det(uv)long	long undervoltage detection time	on pins VCC and/or VIO	[2] [16]	100	-	150	ms
t _{rec(uv)}	undervoltage recovery time	on pin VCC	[2]	-	-	50	μs
		on pin VIO	[2]	-	-	50	μs

- All parameters are guaranteed over the junction temperature range by design. Factory testing uses correlated test conditions to cover the specified [1] temperature and power supply voltage ranges.
- Not tested in production; guaranteed by design.
- [3] If TXD goes LOW before the recessive transition has been completed, the bus switches to dominant.
- The TJA1463 fully meets CiA 601-4:2019 which sets tighter limits for $t_{bit(bus)}$, Δt_{rec} and $\Delta t_{bit(RXD)}$ than ISO 11898-2:2016, which TJA1463 therefore also [4] fully meets.
- 8 Mbit/s specification extends the timing characteristics of ISO 11898-2:2016 and CiA 601-4:2019. [5]
- [6]
- tbit(bus) = $\Delta t_{bit(DUS)} + t_{bit(TXD)}$.
 For reasons related to CAN FD bit timing symmetry, these values are centered around the nominal bit length. Details can be found in document AH2002 'TJx144x/TJx146x Application Hints', available on request from NXP Semiconductors.
- [8]
- $t_{\text{bit}(RXD)} = \Delta t_{\text{bit}(RXD)} + t_{\text{bit}(TXD)}$.
 Time-out occurs between the min and max values. Time-out is guaranteed not to occur below the min value; time-out is guaranteed to occur above the
- [10] A dominant/recessive phase shorter than the min value is guaranteed not be seen as a dominant/recessive bit; a dominant/recessive phase longer than the max value is guaranteed to be seen as a dominant/recessive bit.
- [11] When a wake-up is detected, RXD start-up time is between the min and max values. RXD cannot be relied on below the min value; RXD can be relied on above the max value; see Figure 6.
- [12] INH switches HIGH between the min and max values after a wake-up had been detected. INH is guaranteed to be floating below the min value and guaranteed to be HIGH above the max value; see Figure 6.
- [13] The device is guaranteed to switch to Sleep mode when STB_N = LOW and EN = HIGH for longer than max value, and guaranteed not to switch to Sleep mode when less than the min value.
- The device is guaranteed to wake up above 50 µs and guaranteed not to wake up below 20 µs.
- [15] Pulses shorter than the min value are guaranteed to be filtered out; pulses longer than the max value are guaranteed to be processed.
- [16] An undervoltage longer than the max value is guaranteed to force a transition to Sleep mode; an undervoltage shorter than the min value is guaranteed not to force a transition to Sleep mode.

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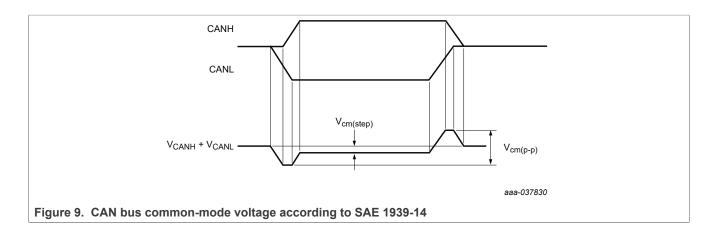


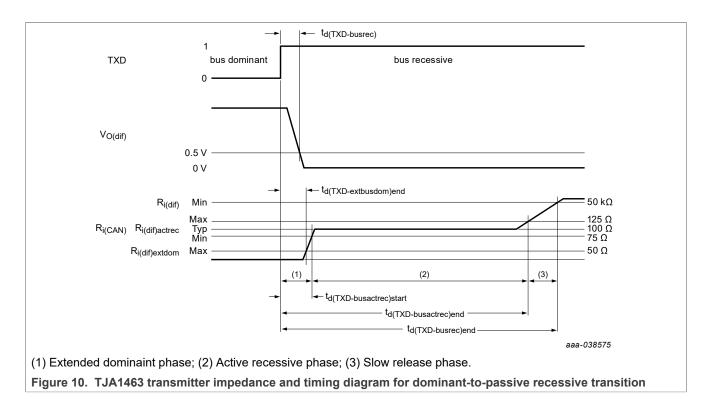


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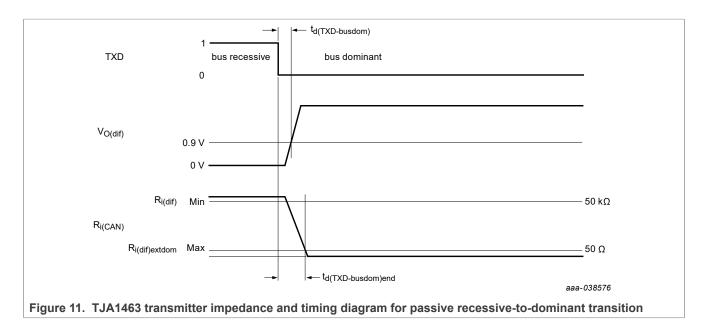
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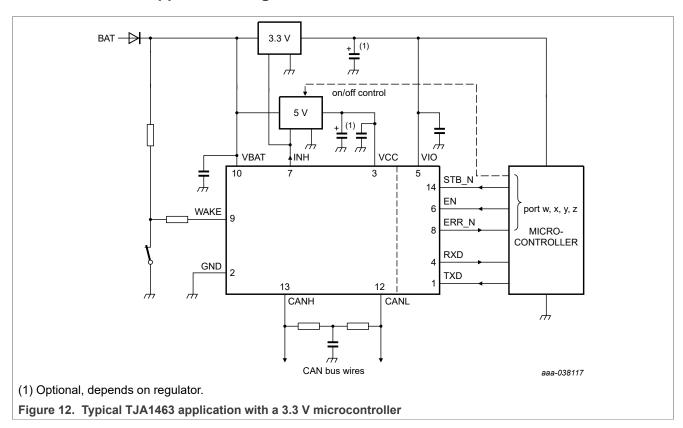


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12 Application information

12.1 Application diagram



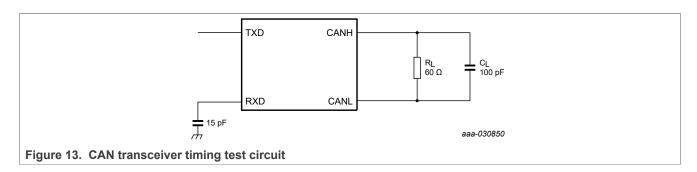
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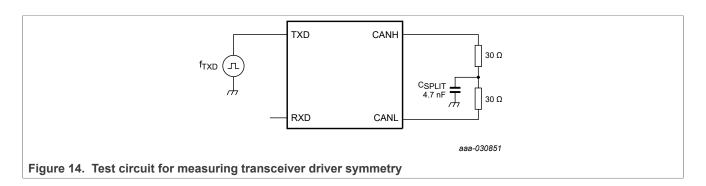
12.2 Application hints

Further information on the application of the TJA1463 can be found in NXP application hints AH2002 'TJx144x/TJx146x Application Hints', available on request from NXP Semiconductors.

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13 Test information



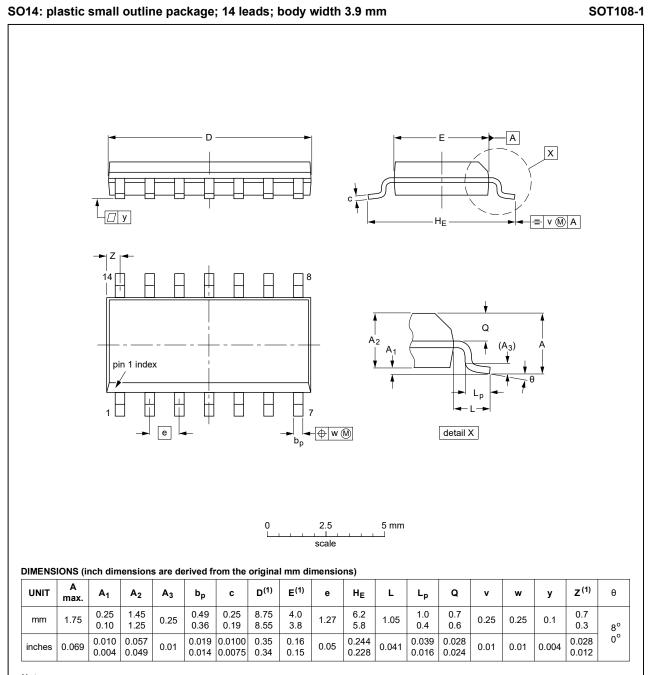


13.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q100 Rev-H - Failure mechanism based stress test qualification for integrated circuits*, and is suitable for use in automotive applications.

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14 Package outline



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

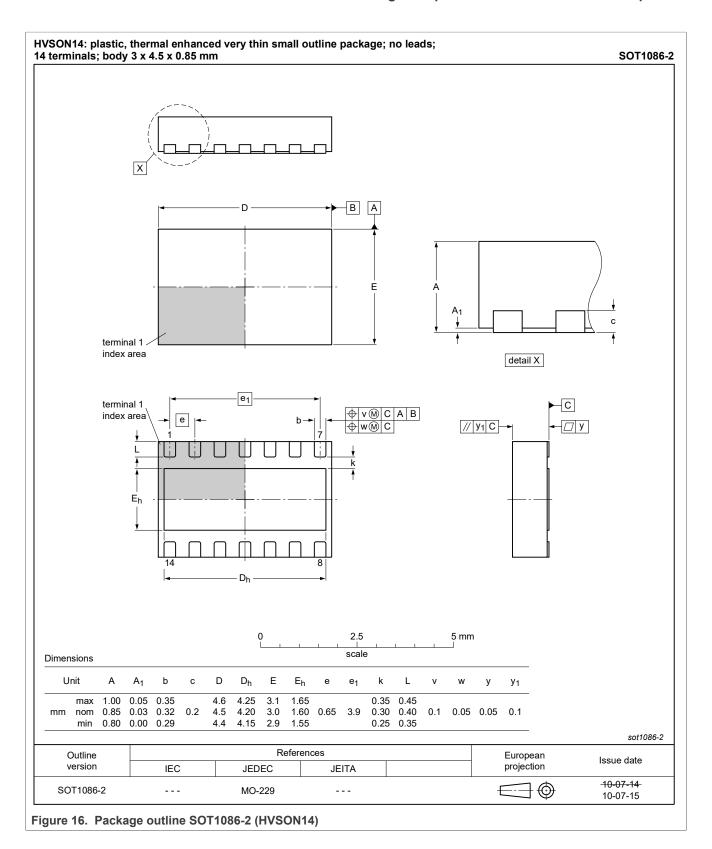
Figure 15. Package outline SOT108-1 (SO14)

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Product data sheet

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15 Handling information

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling ensure that the appropriate precautions are taken as described in *JESD625-A* or equivalent standards.

16 Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

16.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

16.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- · Package footprints, including solder thieves and orientation
- · The moisture sensitivity level of the packages
- · Package placement
- · Inspection and repair
- · Lead-free soldering versus SnPb soldering

16.3 Wave soldering

Key characteristics in wave soldering are:

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- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- · Solder bath specifications, including temperature and impurities

16.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 17</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board
 is heated to the peak temperature) and cooling down. It is imperative that the peak
 temperature is high enough for the solder to make reliable solder joints (a solder
 paste characteristic). In addition, the peak temperature must be low enough that the
 packages and/or boards are not damaged. The peak temperature of the package
 depends on package thickness and volume and is classified in accordance with
 Table 10 and Table 11

Table 10. SnPb eutectic process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)					
	Volume (mm³)					
	< 350	≥ 350				
< 2.5	235	220				
≥ 2.5	220	220				

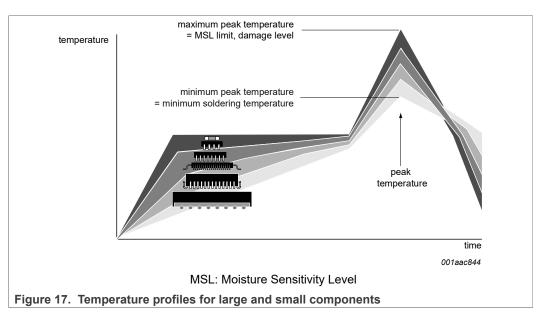
Table 11. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)						
	Volume (mm³)						
	< 350	350 to 2000	> 2000				
< 1.6	260	260	260				
1.6 to 2.5	260	250	245				
> 2.5	250	245	245				

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see <u>Figure 17</u>.

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For further information on temperature profiles, refer to Application Note *AN10365* "Surface mount reflow soldering description".

17 Soldering of HVSON packages

<u>Section 16</u> contains a brief introduction to the techniques most commonly used to solder Surface Mounted Devices (SMD). A more detailed discussion on soldering HVSON leadless package ICs can be found in the following application note:

• AN10365 "Surface mount reflow soldering description"

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18 Appendix: ISO 11898-2:2016 and CiA 601-4:2019 parameter cross-reference lists

Table 12. ISO 11898-2:2016 to NXP data sheet parameter conversion

ISO 11898-2:2016		NXP data sheet			
Parameter	Notation	Symbol	Parameter		
HS-PMA dominant output characteristics					
Single ended voltage on CAN_H	V _{CAN_H}	V _{O(dom)}	dominant output voltage		
Single ended voltage on CAN_L	V _{CAN_L}				
Differential voltage on normal bus load	V_{Diff}	V _{O(dif)}	differential output voltage		
Differential voltage on effective resistance during arbitration					
Optional: Differential voltage on extended bus load range					
HS-PMA driver symmetry					
Driver symmetry	V _{SYM}	V _{TXsym}	transmitter voltage symmetry		
Maximum HS-PMA driver output current					
Absolute current on CAN_H	I _{CAN_H}	I _{O(sc)}	short-circuit output current		
Absolute current on CAN_L	I _{CAN_L}				
HS-PMA recessive output characteristics, bus biasing ac	ctive/inacti	ve	1		
Single ended output voltage on CAN_H	V _{CAN_H}	V _{O(rec)}	recessive output voltage		
Single ended output voltage on CAN_L	V _{CAN_L}				
Differential output voltage	V_{Diff}	V _{O(dif)}	differential output voltage		
Optional HS-PMA transmit dominant time-out					
Transmit dominant time-out, long	t _{dom}	$t_{to(dom)TXD}$	TXD dominant time-out time		
Transmit dominant time-out, short					
HS-PMA static receiver input characteristics, bus biasing	g active/ina	active			
Recessive state differential input voltage range Dominant state differential input voltage range	V_{Diff}	$V_{th(RX)dif}$	differential receiver threshold voltage		
		V _{rec(RX)}	receiver recessive voltage		
		$V_{dom(RX)}$	receiver dominant voltage		
HS-PMA receiver input resistance (matching)					
Differential internal resistance	R _{Diff}	R _{i(dif)}	differential input resistance		
Single ended internal resistance	R _{CAN_H} R _{CAN_L}	R _i	input resistance		
Matching of internal resistance	MR	ΔR_i	input resistance deviation		
HS-PMA implementation loop delay requirement					
Loop delay	t _{Loop}	t _{d(TXDH-RXDH)}	delay time from TXD HIGH to RXD HIGH		
		t _{d(TXDL-RXDL)}	delay time from TXD LOW to RXD LOW		

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Table 12. ISO 11898-2:2016 to NXP data sheet parameter conversion...continued

ISO 11898-2:2016	NXP data she	et		
Parameter	Symbol	Parameter		
Optional HS-PMA implementation data signal timing requ Mbit/s and above 2 Mbit/s up to 5 Mbit/s	uirements	for use with bit	rates above 1 Mbit/s up to 2	
Transmitted recessive bit width @ 2 Mbit/s / @ 5 Mbit/s, intended	t _{Bit(Bus)}	t _{bit(bus)}	transmitted recessive bit width	
Received recessive bit width @ 2 Mbit/s / @ 5 Mbit/s	t _{Bit(RXD)}	t _{bit(RXD)}	bit time on pin RXD	
Receiver timing symmetry @ 2 Mbit/s / @ 5 Mbit/s	Δt_{Rec}	Δt_{rec}	receiver timing symmetry	
HS-PMA maximum ratings of V_{CAN_H} , V_{CAN_L} and V_{Diff}				
Maximum rating V _{Diff}	V_{Diff}	V _(CANH-CANL)	voltage between pin CANH and pin CANL	
General maximum rating V _{CAN_H} and V _{CAN_L}	V _{CAN_H}	V _x	voltage on pin x	
Optional: Extended maximum rating VCAN_H and VCAN_L	V_{CAN_L}			
HS-PMA maximum leakage currents on CAN_H and CAN	_L, unpow	ered		
Leakage current on CAN_H, CAN_L	I _{CAN_H}	IL	leakage current	
HS-PMA bus biasing control timings				
CAN activity filter time, long	t _{Filter}	t _{wake(busdom)} [1]	bus dominant wake-up time	
CAN activity filter time, short		t _{wake(busrec)}	bus recessive wake-up time	
Wake-up time-out, short	t _{Wake}	t _{to(wake)bus}	bus wake-up time-out time	
Wake-up time-out, long				

 $^{[1] \}hspace{0.5cm} \textbf{t}_{\text{fltr}(\text{wake})\text{bus}} \text{ - bus wake-up filter time, in devices with basic wake-up functionality}$

Table 13. CiA 601-4:2019 to NXP data sheet parameter conversion

CiA 601-4:2019	NXP data sheet						
Parameter	Notation	Symbol	Parameter				
Optional HS-PMA implementation data signal timing requirements							
Signal improvement time TX-based	t _{SIC_TX_base}	t _{d(TXD-busrec)end}	delay time from TXD to bus recessive end				
Signal improvement time RX-based	t _{SIC_RX_base}	N/A ^[1]	N/A				
Transmitted bit width variation	Δt _{Bit(Bus)}	$\Delta t_{bit(bus)}$	transmitted recessive bit width deviation				
Received bit width variation	$\Delta t_{Bit(RxD)}$	$\Delta t_{bit(RXD)}$	received recessive bit width deviation				
Receiver timing symmetry	Δt_{REC}	Δt_{rec}	receiver timing symmetry				
Propagation delay from TXD to bus dominant	t _{prop(TxD-busdom)}	$t_{d(TXD-busdom)}$	delay time from TXD to bus dominant				
Propagation delay from TXD to bus recessive	t _{prop(TxD-busrec)}	t _{d(TXD-busrec)}	delay time from TXD to bus recessive				
Propagation delay from bus to RXD dominant	t _{prop(busdom-RXD)}	t _{d(busdom-RXD)}	delay time from bus dominant to RXD				
Propagation delay from bus to RXD recessive	t _{prop(busrec-RXD)}	t _{d(busrec-RXD)}	delay time from bus recessive to RXD				

^[1] The NXP signal improvement implementation is TX-based; RX-based is not applicable.

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19 Appendix: TJx144x/TJx146x/TJF1441 family overview

Table 14. Feature overview of the complete TJx144x/TJx146x/TJF1441 family

	Mode	es				Supp	lies		Data	rate	Addit	ional f	eatures	S		
Device ^[1]	Normal	Standby	Sleep	Silent/Listen-only	Selectable Off	VCC pin	VIO pin	VBAT pin	Up to 5 Mbit/s CAN FD	Up to 8 Mbit/s CAN FD ^[2]	Signal improvement ^[3]	Wake-up source recognition ^[4]	Short WUP support [0.5 - 1.8 µs] ^[5]	Single supply pin wake-up ^[6]	TXD dominant timeout	Local diagnostics via ERR_N pin
TJx1441A	•			•		•	•		•						•	
TJx1441B	•			•		•			•						•	
TJx1441D	•			•	•	•			•						•	
TJF1441A	•			•		•	•		•						[7]	
TJx1442A	•	•				•	•		•				•	•	•	
TJx1442B	•	•				•			•				•		•	
TJx1443A	•	•	•	•		•	•	•	•			•	•	•	•	•
TJx1448A	•	•				•	•		•				•	•	•	
TJx1448B	•	•				•			•				•		•	
TJx1448C	•	•				•	•		•			•	•	•	•	
TJx1462A	•	•				•	•		•	•	•		•	•	•	
TJx1462B	•	•				•			•	•	•		•		•	
TJx1463A	•	•	•	•		•	•	•	•	•	•	•	•	•	•	•

TJx: TJA14xxx is AEC-Q100 Grade 1; TJR14xxx is AEC-Q100 Grade 0; TJF1441A is non-automotive grade. Only guaranteed for TJA146x, AEC-Q100 Grade 1.

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CAN FD Signal Improvement Capability (SIC) according to CiA 601-4:2019.

RXD is held LOW after wake-up request, enabling wake-up source recognition.

WUP = wake-up pattern according ISO11898-2:2016.

Only VIO supply needed for wake-up in TJA1442A, TJA1448A, TJA1448C, TJA1462A; only VBAT supply needed for wake-up in TJA1443A, TJA1463A.

Not having TXD dominant timeout allows for very low data rates in non-automotive grade applications.

CAN FD signal improvement transceiver with Sleep mode

20 Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TJA1463 v.2	20211015	Product data sheet	-	TJA1463 v.1
Modifications	 t_{bit(BUS)}, Δt_{rec} and Added device (<u>Ta</u> <u>Figure 3</u>: text def <u>Section 7.1.1.2</u>: t <u>Table 6</u>: table no changed for para <u>Table 9</u>: measure added 	nication up to 8 Mbit/s: Section I t _{bit(RXD)} updated in Table 9 and able 3) and family (Section 19) ining transition from Sleep to Sypo corrected - STBN_N changes 3 and 4 revised; table note meter V _{trt} ement conditions for parameter bibility for use in Automotive approximates and the state of the section of the sect	d table note 5 added feature overviews standy revised ged to STB_N 12 added; measurement of startup(RXD) and tstartup(INF)	conditions and table note
TJA1463 v.1	20200812	Product data sheet	-	-

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21 Legal information

21.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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